/ E E L L

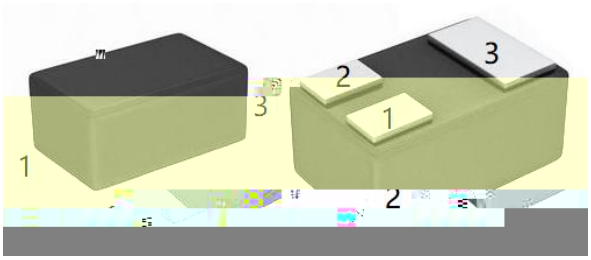
DFN1006-3L N MOS

N-Channel Enhancement Mode Field Effect Transistor in a DFN1006-3L Plastic Package.

2KV

Sensitive gate trigger current and Low Holding current.ESD protected up to 2KV.HF Product.

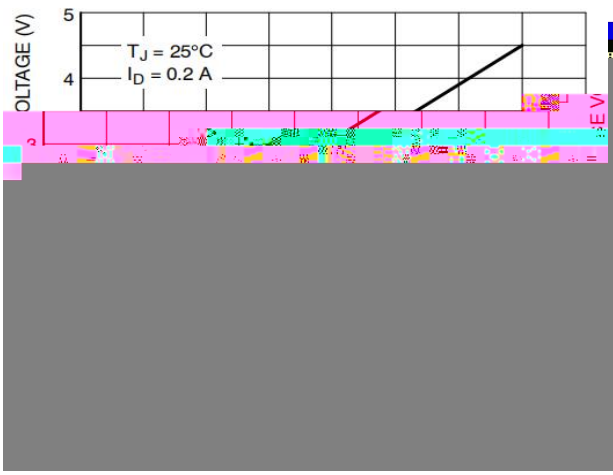
Intended for use in general purpose switching and phase control applications.



Pin1:G Pin2:S Pin3:D

See Marking Instructions.

/ Electrical Characteristic Curve



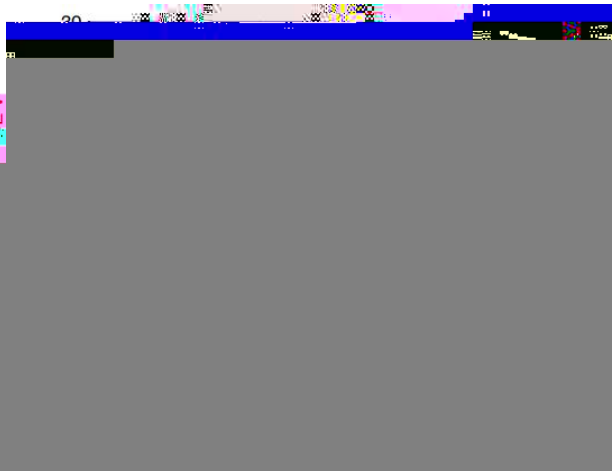
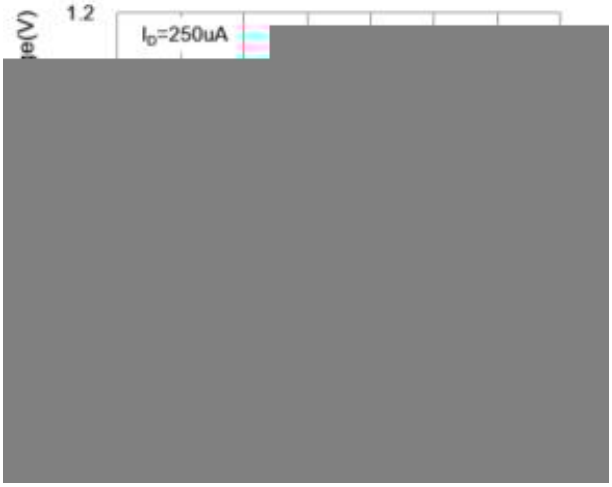
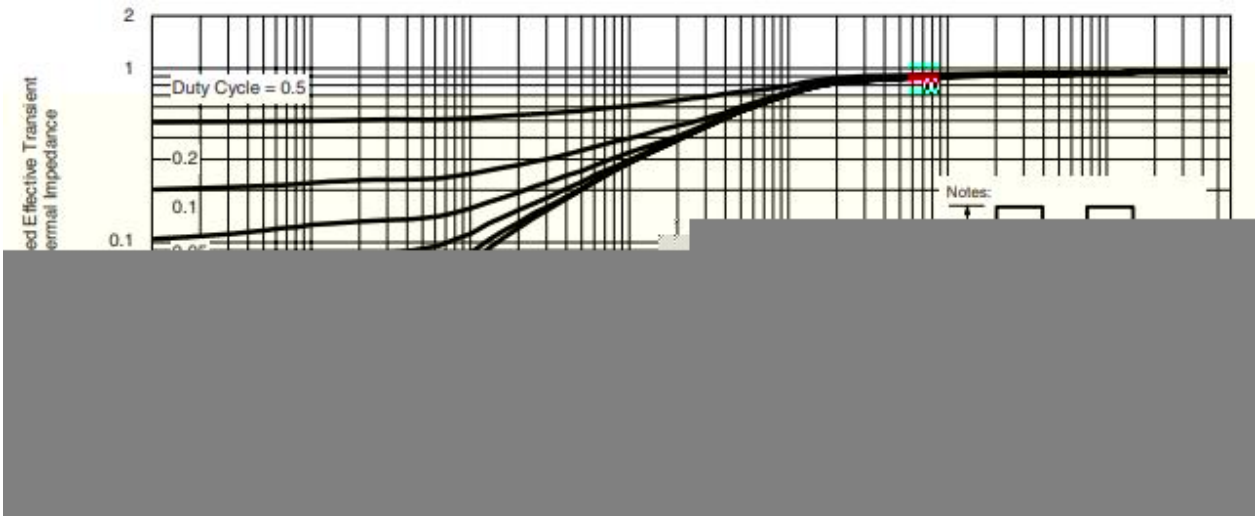


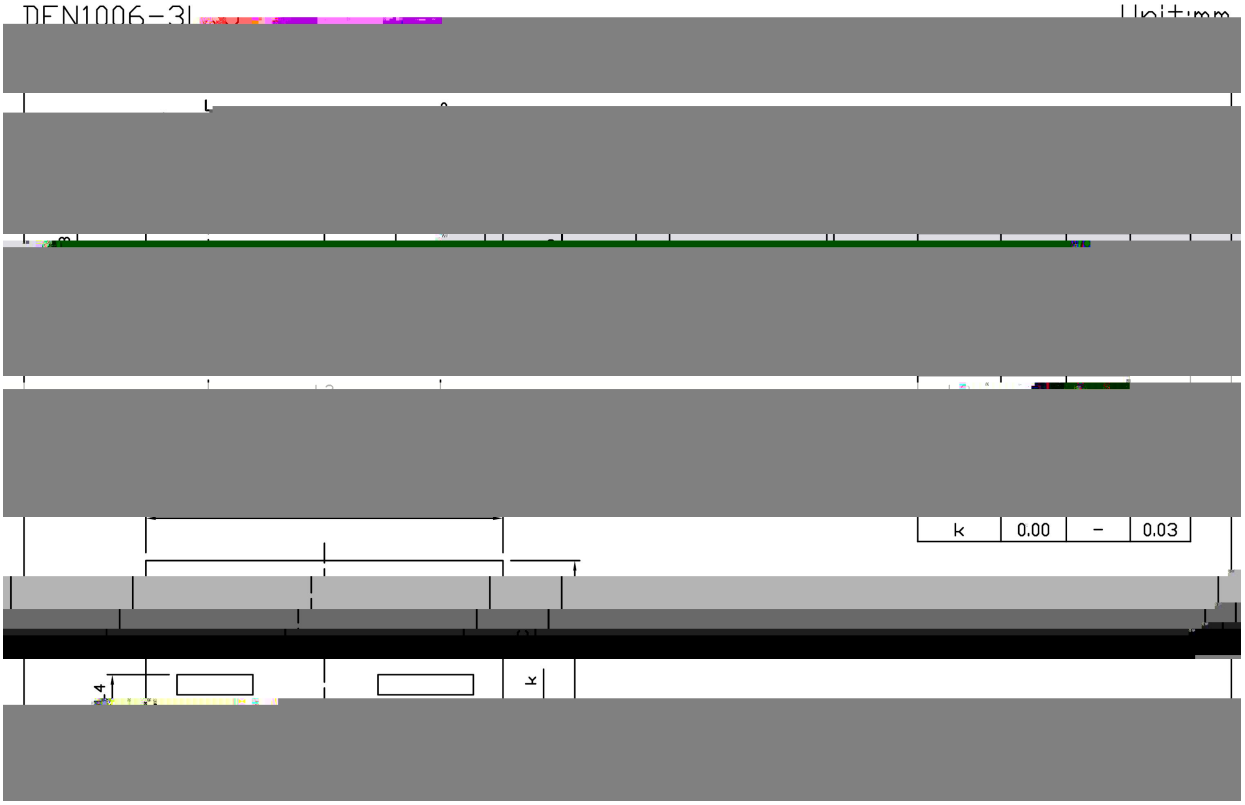


Figure 9 : Safe Operation Area





/ Package Dimensions



/ Marking Instructions



702K2

Note:

702K2: Product Type